



# Cold sintered, temperature-stable $\text{CaSnSiO}_5\text{-K}_2\text{MoO}_4$ composite microwave ceramics and its prototype microstrip patch antenna

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## ARTICLE INFO

### Keywords:

Microwave dielectric  
Cold sintering process  
Microstrip patch antenna

## ABSTRACT

Dense  $(1-x)\text{wt}\%\text{CaSnSiO}_5\text{-}x\text{wt}\%\text{K}_2\text{MoO}_4$  (CSSO-KMO) composite ceramics were fabricated by the cold sintering process at  $180^\circ\text{C}$  under 400 MPa for 60 min. X-ray diffraction, Energy dispersive X-ray and Raman spectroscopy confirmed that CSSO and KMO coexisted without intermediate phases. As KMO weight fraction increased, relative permittivity ( $\epsilon_r$ ) and temperature coefficient of resonant frequency ( $\tau_f$ ) decreased and the microwave quality factor ( $Q \times f$ , where  $f$  is resonant frequency) increased. Near-zero  $\tau_f$  ( $-0.5 \text{ ppm}/^\circ\text{C}$ ) was obtained for 65 wt %CSSO-35 wt%KMO with  $\epsilon_r \sim 9.2$  and  $Q \times f \sim 6240 \text{ GHz}$ . No chemical reaction between ceramic composites and silver was observed, demonstrating potential for cofiring with Ag-paste. A prototype antenna was fabricated from 65 wt%CSSO-35 wt%KMO composite ceramic with a bandwidth of 144 MHz @ -10 dB, a gain of 5.7 dBi and a total efficiency of 88.4 % at 5.2 GHz, suitable for 5 G mobile communication systems.

## 1. Introduction

Microwave dielectric ceramics are commonly used in communication systems in components such as antennas, duplexers, resonators and substrates [1,2]. With the development of fifth-generation technology for cellular networks (5 G), faster and more reliable broadband access is required with larger capacity and shorter transmission response time (delay less than 1 ms). To reduce the signal delay of the system, it is necessary to optimize the signal transmission response mode, system structure and physical hardware. The propagation speed of electromagnetic waves is inversely proportional to the relative permittivity ( $\epsilon_r$ ) and low  $\epsilon_r$  values minimize the cross-coupling between air and dielectrics for 5 G applications. At the same time, high microwave quality factor ( $Q \times f$ , where  $f$  is the resonant frequency) improves selectivity and energy transmission, and near zero temperature coefficient of resonant frequency ( $\tau_f$ ) maintains temperature stability of components in operation [3–10]. Temperature-stable silicates such as  $\text{Ca}_2\text{Al}_2\text{SiO}_7$  [11],  $\text{Y}_3\text{MgAl}_3\text{SiO}_{12}$  [12],  $\text{Mg}_2\text{SiO}_4$  [13] and  $(\text{Sr,Ba})\text{Y}_2\text{Si}_3\text{O}_{10}$  [14] with low  $\epsilon_r$

(4–15) and high  $Q \times f$  (20,000–240,000 GHz) have therefore, attracted attention as candidates for 5G applications. However, silicate-based ceramics are conventionally sintered at high temperatures ( $> 1200^\circ\text{C}$ ), consuming energy and releasing carbon. The cold sintering process (CSP) can densify ceramics and composites at ultralow temperatures ( $< 200^\circ\text{C}$ ), temperatures that not only reduce carbon emissions but also facilitate direct deposition onto printed circuit boards [15–27].

$\text{CaSnSiO}_5$  (CSSO) is conventionally sintered at  $1450^\circ\text{C}$  with  $\epsilon_r \sim 10.9$ ,  $\tau_f \sim 35 \text{ ppm}/^\circ\text{C}$ ,  $Q \times f \sim 43,600 \text{ GHz}$  [28,29] and is therefore, an ideal base to begin the search for cold sintered silicates. However, initial cold sintering studies of CSSO were unsuccessful and hence, following work by Wang and co-workers [26,27],  $\text{K}_2\text{MoO}_4$  (KMO) was used as a fluxing agent to encourage densification and to tune  $\tau_f$  to near zero. The microstructure, Ag compatibility and microwave dielectric properties of CSSO-KMO composites were therefore, investigated followed by the design, fabrication and testing of a prototype microstrip patch antenna on substrates made from optimum compositions.

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<https://doi.org/10.1016/j.jeurceramsoc.2020.08.053>

Received 15 June 2020; Received in revised form 17 August 2020; Accepted 22 August 2020

Available online 25 August 2020

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## 2. Experimental Section

(1-x)wt%CSSO-xwt%KMO ( $x = 20, 30, 35, 40, 50, 60, 70, 80, 90$  and 100) composite ceramics were prepared by CSP. CSSO powder was synthesized by a traditional high-temperature solid-state method. The raw materials,  $\text{CaCO}_3$  (Acros Organics, 99.99 %),  $\text{SiO}_2$  (Acros Organics, 99.99 %) and  $\text{SnO}_2$  (Acros Organics, 99.99 %) were weighed according to the stoichiometric ratio of  $\text{CaCO}_3 : \text{SiO}_2 : \text{SnO}_2 = 1:1:1$ , and then planetary ball-milled 4 h in isopropanol. The mixed powders were dried and calcined at  $1450^\circ\text{C}$  for 4 h to synthesize the CSSO powders. To obtain fine and uniform CSSO powders, the calcined CSSO powders were re-milled 4 h, dried, and then sieved using a  $48\ \mu\text{m}$  Nylon screen. CSSO and KMO (Alfa Aesar, > 99 %) powders were weighed and mixed with  $\sim 15\ \text{wt}\%$  deionized water. CSSO-KMO composite ceramics were obtained by hot-pressing mixed powders in a 12 mm die at  $180^\circ\text{C}$  for 60 min under a uniaxial pressure of 400 MPa, after which samples were placed in an oven at  $120^\circ\text{C}$  for 24 h to remove residual moisture. Furthermore, in order to reveal the chemical compatibility, a Heraeus LTC3602 low temperature Ag paste was printed between two green pellets, and then cofired by cold sintering to form a sandwich structure.

The geometric method was used to calculate the bulk density of composite ceramics [30–32]. X-ray powder diffraction (XRD, D2 Phaser, Bruker) using  $\text{CuK}\alpha$  radiation was employed to identify crystal structure and phase composition. Scanning electron microscope (SEM, Inspect F50, FEI) equipped with energy dispersive spectroscopy (EDS) was used to examine the microstructure on the polished surface and cross section of composite ceramics. Raman spectra were collected at room temperature using a Raman spectrometer (LabRAM HR800) excited with an  $\text{Ar}^+$  laser (514.5 nm). Temperature and frequency dependence of  $\epsilon_r$  was measured using an Agilent 4294A impedance analyzer from room temperature to  $250^\circ\text{C}$ . Impedance spectroscopy was performed using an Agilent E4980A impedance AC analyzer from 20 to  $10^6\ \text{Hz}$ . A vector network analyzer (R3767CH, Advantest Corporation, Tokyo, Japan) was measured the microwave properties of the composite ceramics by the  $\text{TE}_{01\delta}$  dielectric resonator method. The cavity was heated by Peltier device and the resonance frequency ( $f$ ) was measured in the range from 25 to  $85^\circ\text{C}$ . The following formula was used to obtain the corresponding  $\tau_f$  value:

$$\tau_f = \frac{f_T - f_{T0}}{f_{T0} \times (T_T - T_{T0})} \times 10^6 (\text{ppm}/^\circ\text{C}) \quad (1)$$

where  $f_{T0}$  and  $f_T$  represent  $f$  at  $T_0$  ( $25^\circ\text{C}$ ) and  $T$  ( $85^\circ\text{C}$ ), respectively.

## 3. Results and discussion

Fig. 1 shows the XRD patterns of synthesized CSSO powder, KMO raw powder and cold-sintered CSSO-KMO composites. Both CSSO (space group  $A2/a$ , JCPDS No.86–0928) and KMO (space group  $C12/m1$ , JCPDS No.29–1021) have a monoclinic structure [26–29]. All diffraction peaks in the XRD patterns belong to CSSO and KMO with no peaks from impurity phases detected. The intensity of KMO peaks increases as a function of its weight fraction.

Fig. 2 displays the Raman spectra of cold-sintered (1-x)CSSO-xKMO composite ceramics at room temperature. According to group theory and irreducible representation, CSSO and KMO have 45 and 39 different vibration modes, respectively.

$$\Gamma_{\text{CSSO}} = 9A_g + 11A_u + 12B_g + 13B_u \quad (2)$$

$$\Gamma_{\text{KMO}} = 13A_g + 7A_u + 8B_g + 11B_u \quad (3)$$

The main Raman bands of CSSO are located at 135, 175, 295, 323, 363, 443, 510, 572 and  $740\ \text{cm}^{-1}$ , which are attributed to bending modes of the Ca-O bond (135, 175 and  $295\ \text{cm}^{-1}$ ),  $[\text{SiO}_4]^{4-}$  modes (443 and  $510\ \text{cm}^{-1}$ ) and  $[\text{SnO}_6]$ - polyhedral modes (323, 363, 572 and  $740\ \text{cm}^{-1}$ ) [33,34]. For KMO, Raman bands of  $100 \sim 160\ \text{cm}^{-1}$  are

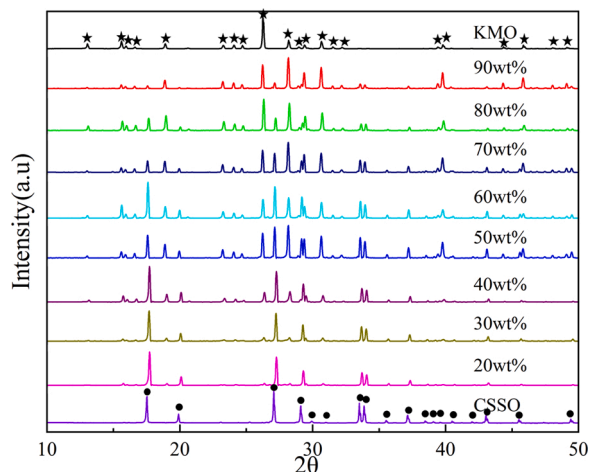


Fig. 1. Room-temperature XRD patterns of (1-x)CSSO-xKMO composite ceramics fabricated by CSP, and CSSO powder synthesized by solid state reaction.

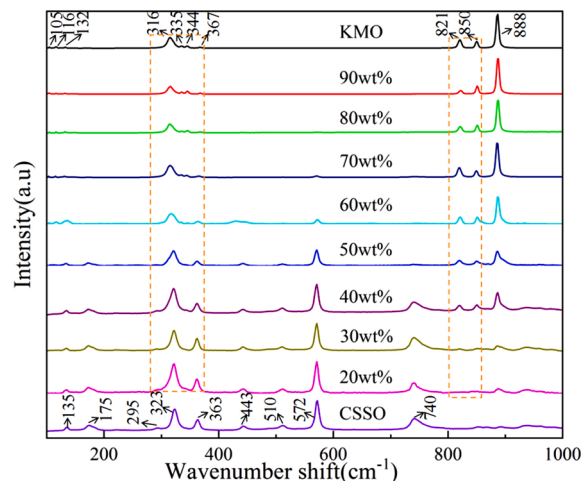
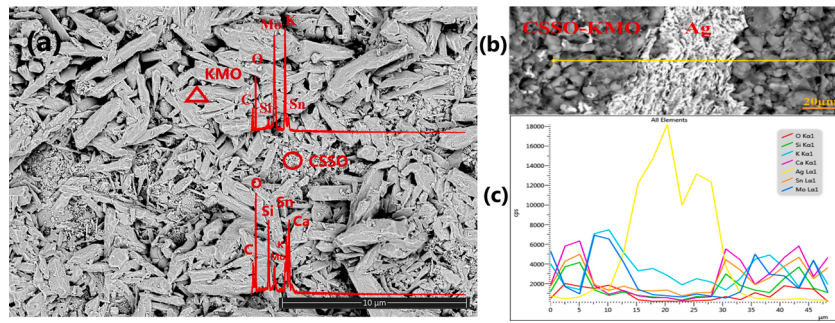


Fig. 2. Raman spectra of (1-x)CSSO-xKMO composite ceramics.

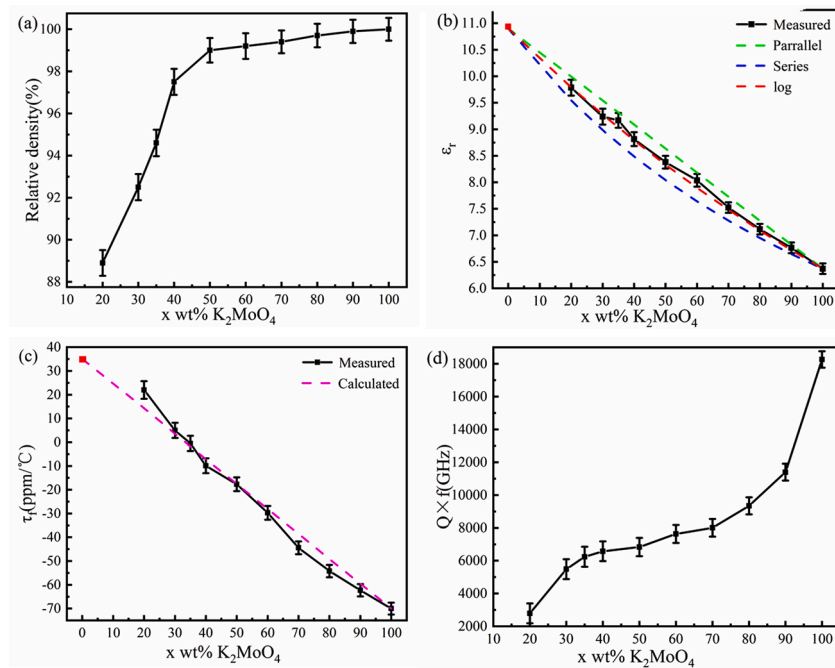
attributed to translations and vibrations modes of  $\text{MoO}_4$  tetrahedra and translations of  $\text{K}^+$ , bands at  $310 \sim 370\ \text{cm}^{-1}$  belong to bending modes of  $\text{MoO}_4$  tetrahedra and modes at  $820 \sim 890\ \text{cm}^{-1}$  are assigned to stretching modes of  $\text{MoO}_4$  tetrahedra [35,36]. As KMO concentration increases, the intensity of KMO Raman modes increases (as marked in orange frame) and all data except the end-members remains consistent with a two-phase mix with CSSO.

Fig. 3(a) presents the SEM images of cold-sintered 70 wt%CSSO-30 wt%KMO composite ceramics. EDS spectra showed the elongated needle or sheet-shaped radial grains belong to KMO (indexed triangle shape), and the aggregated grains are CSSO (indexed circle shape). To verify the compatibility of cold-sintered (1-x)CSSO-xKMO composite ceramics with Ag electrodes, Ag powder was cold-sintered with 65 wt% CSSO-35 wt%KMO powder, Fig. 3(b). The white area is the Ag electrode layer, which has a clean interface with CSSO-KMO ceramic particles. EDS line scans suggest that there is no interact between Ag and CSSO-KMO composite, Fig. 4(c), indicating good chemical compatibility with Ag electrode.

The relative density ( $\rho_r$ ) and microwave dielectric properties of (1-x)CSSO-xKMO composite ceramics as a function of KMO weight fraction are plotted in Fig. 4.  $\rho_r$  increases from 89 % for 80 wt%CSSO-20 wt% KMO to near 100 % for KMO.  $\epsilon_r$  and  $\tau_f$  decrease linearly as KMO weight fraction increases, while  $Q \times f$  increases, Table 1. Near-zero  $\tau_f$  ( $-0.5\ \text{ppm}/^\circ\text{C}$ ) is obtained for 65 wt%CSSO-35 wt%KMO composites with  $\epsilon_r \sim$



**Fig. 3.** (a) SEM and EDS of etched polished surface of 70 wt%CSSO-30 wt%KMO sample (Triangle KMO, Circle CSSO); (b) SEM of the cross section of 65 wt%CSSO-35 wt%KMO sample co-sintered with silver, and (c) EDS elemental line.



**Fig. 4.** Microwave dielectric properties of (1-x)CSSO-xKMO composite ceramics as a wt fraction of KMO.

9.168 and  $Q \times f \sim 6240$  GHz. According to the XRD, Raman and EDS, there are no chemical interactions between the two phases. Thus, the effective  $\epsilon_r$  can be estimated by the Lichtenecker mixing law [37]:

$$\text{parallel mixing law, } \epsilon = V_1 \epsilon_1 + V_2 \epsilon_2 \quad (4)$$

$$\text{series mixing law, } 1/\epsilon = V_1/\epsilon_1 + V_2/\epsilon_2 \quad (5)$$

$$\text{logarithmic mixing law, } \epsilon = \epsilon_1 V_1 \epsilon_2 V_2 \ln \epsilon, \ln \epsilon = V_1 \ln \epsilon_1 + V_2 \ln \epsilon_2 \quad (6)$$

**Table 1**

Sintering temperature (ST), relative density ( $\rho_r$ ), and microwave dielectric properties of (1-x)CSSO-xKMO ceramics.

Composition	ST(°C)	$\rho_r$ (%)	$\epsilon_r$	$Q \times f$ (GHz)	$\tau_f$ (ppm/°C)
CaSnSiO <sub>5</sub>	1450	95	10.9	43,600	+35
20 wt%K <sub>2</sub> MoO <sub>4</sub>	180	89	9.78	2792	+22
30 wt%K <sub>2</sub> MoO <sub>4</sub>	180	93	9.24	5484	+5
35 wt%K <sub>2</sub> MoO <sub>4</sub>	180	95	9.17	6240	-0.5
40 wt%K <sub>2</sub> MoO <sub>4</sub>	180	98	8.82	6576	-9.9
50 wt%K <sub>2</sub> MoO <sub>4</sub>	180	99	8.38	6831	-18
60 wt%K <sub>2</sub> MoO <sub>4</sub>	180	99	8.04	7628	-30
70 wt%K <sub>2</sub> MoO <sub>4</sub>	180	99	7.52	8004	-44
80 wt%K <sub>2</sub> MoO <sub>4</sub>	180	100	7.12	9343	-54
90 wt%K <sub>2</sub> MoO <sub>4</sub>	180	100	6.76	11,395	-62
K <sub>2</sub> MoO <sub>4</sub>	150	100	6.37	18,266	-70

where  $\epsilon_1$  and  $\epsilon_2$  are the dielectric constants of phase 1 and phase 2, respectively.  $V_1$  and  $V_2$  ( $V_1 + V_2 = 1$ ) are the volume fractions of phase 1 and phase 2 respectively. From Fig. 4(b),  $\epsilon_r$  of (1-x)CSSO-xKMO composite ceramics is less than the calculated value of Eq. (4), larger than the calculated value of Eq. (5), and close to that obtained using Eq. (6), which shows that  $\epsilon_r$  follows the logarithmic mixing law.  $\tau_f$  may be predicted according to parallel mixing rules,

$$\tau_f = V_1 \tau_{f1} + V_2 \tau_{f2} \quad (7)$$

where  $\tau_{f1}$  and  $\tau_{f2}$  correspond to the  $\tau_f$  of phase 1 and phase 2, respectively, as presented in Fig. 4(c).

Fig. 5 shows the temperature dependence of  $\epsilon_r$  for 65 wt%CSSO-35 wt%KMO measured from 10 kHz to 1 MHz.  $\epsilon_r$  is stable from room temperature to 250 °C, as shown in Fig. 7a, indicating no phase transition in this temperature range but decreases with increase in frequency as space charge contributions diminish (Fig. 5b). At room temperature,  $\epsilon_r$  @ 1 MHz is 10.8, close to the value at microwave frequencies in Table 1 (9.17).

Room temperature EIS of 65 wt%CSSO-35 wt%KMO is shown in Fig. 6. The complex impedance is divided into real part ( $Z'$ ) and imaginary part ( $Z''$ ) and is expressed by the following formula.

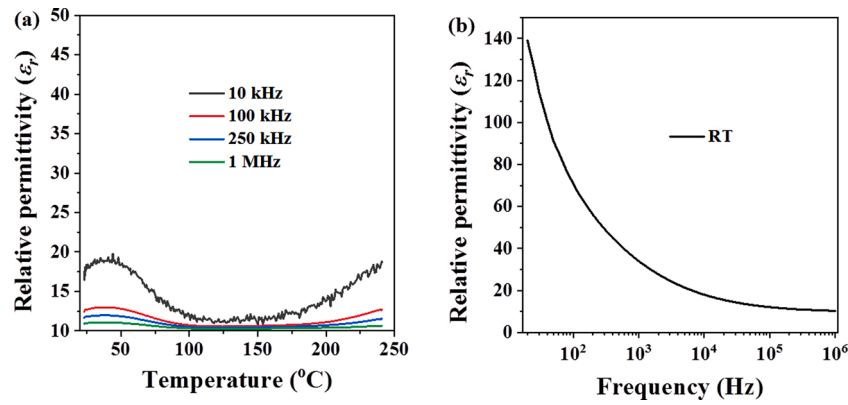


Fig. 5. (a) Temperature dependence, (b) Frequency dependence of  $\epsilon_r$  for 65 wt%CSSO- 35 wt%KMO ceramic.

$$Z = \frac{R}{1 + i\omega RC} = Z' - iZ'' \quad (8)$$

$$Z' = \frac{R}{1 + (\omega RC)^2} \quad (9)$$

$$Z'' = \frac{\omega R^2 C}{1 + (\omega RC)^2} \quad (10)$$

where  $\omega$  is angular frequency. From Fig. 7(a), the observed non-perfect semicircle is equal to the sum of two smaller semicircles, corresponding to two Debye peaks in frequency dependence of  $Z''$  and  $M''$ , Fig. 6(b), which indicates at least two electrical components. The extracted capacitances of these two components are  $2.6 \times 10^{-12}$  F cm<sup>-1</sup> and  $1.7 \times 10^{-12}$  F cm<sup>-1</sup> for component 1 and 2, respectively. The complex microstructure of the CSSO-KMO make attributing the components to a specific part of the microstructure difficult but the low temperature, low frequency response is consistent with the space-charge contribution observed in the LCR data, Fig. 5, which decreases with increasing frequency and is absent in MW measurements, Fig. 4.

A 5 G prototype microstrip patch antenna (MSPA) with a center operating frequency of 5.2 GHz was designed and fabricated using the 65 wt%CSSO-35 wt%KMO ceramic as a substrate. The radiation element (the patch) and the ground plane was made of adhesive copper tape. The patch had the dimensions of 11.71 mm x 11.55 mm and the feed point was 3.75 mm away from the patch edge. A semi-rigid coaxial cable (RG405) was used for providing the probe feeding. The thickness of 65 wt%CSSO-35 wt%KMO ceramic substrate was 1.45 mm. The fabricated MSPA is shown in the inset pattern of Fig. 7(a).

The measured and simulated S11 result is shown in Fig. 7(a), indicating a good agreement between the measurement and simulation. The MSPA also shows the good impedance match, with a -10 dB bandwidth of 144 MHz. The MSPA was measured in a Spherical Near-Field anechoic

chamber. The measured radiation patterns at 5.2 GHz at two principle cut planes: magnetic plane (H-plane) and electric plane (E-plane) are shown in Fig. 7(b) and Fig. 7(d), respectively, compared with simulated results. Good agreement between simulation and measurement is observed. The measured antenna gain, directivity and total efficiency (including the impedance mismatch) are shown in Fig. 7(c). The MSPA has an antenna gain of 5.7 dBi and total efficiency of 88.4 % at 5.2 GHz. The far-field performance suggests that 65 wt%CSSO-35 wt%KMO is a good candidate for antenna applications.

#### 4. Conclusions

(1-x)CSSO-xKMO microwave composite ceramics with 89 %–100 % relative density were successfully fabricated by CSP (180 °C, 60 min and 400 MPa). SEM showed that the composite ceramics had a dense microstructure. XRD, EDS and Raman spectra identified two discrete phases of CSSO and KMO, with no chemical interaction. With increasing weight fraction of KMO,  $\epsilon_r$  and  $\tau_f$  decreased, while  $Q \times f$  increased. A near-zero  $\tau_f \sim -0.5$  ppm/°C was obtained in 65 wt%CSSO-35 wt%KMO with  $\epsilon_r \sim 9.17$  and  $Q \times f \sim 6240$  GHz.  $\epsilon_r$  was stable from room temperature to 250 °C but decreased in respect to frequency, consistent with a low temperature, low frequency space charge contribution observed in EIS data. CSSO-KMO composite ceramics and Ag electrodes had good compatibility. A MSPA was designed and fabricated using cold sintered 65 wt%CSSO-35 wt%KMO as a substrate with a central operating frequency of 5.2 GHz. The antenna had an S11 of -10 dB with bandwidth of 144 MHz. The antenna gain of the MSPA was 5.7 dBi at 5.2 GHz, and the total efficiency was 88.4 %.

#### Declaration of Competing Interest

The authors declare that they have no known competing financial

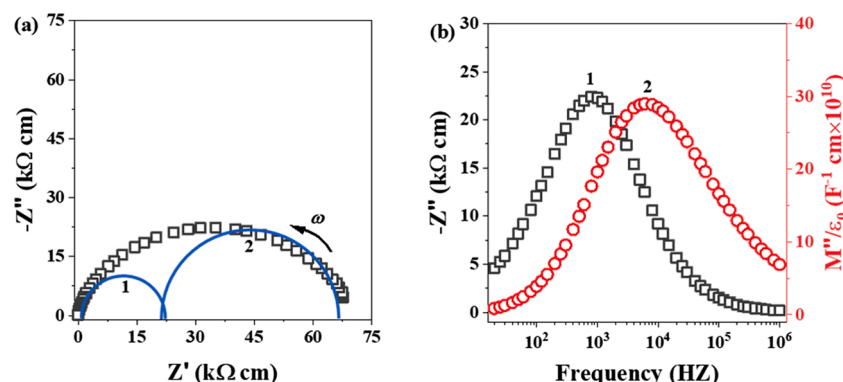
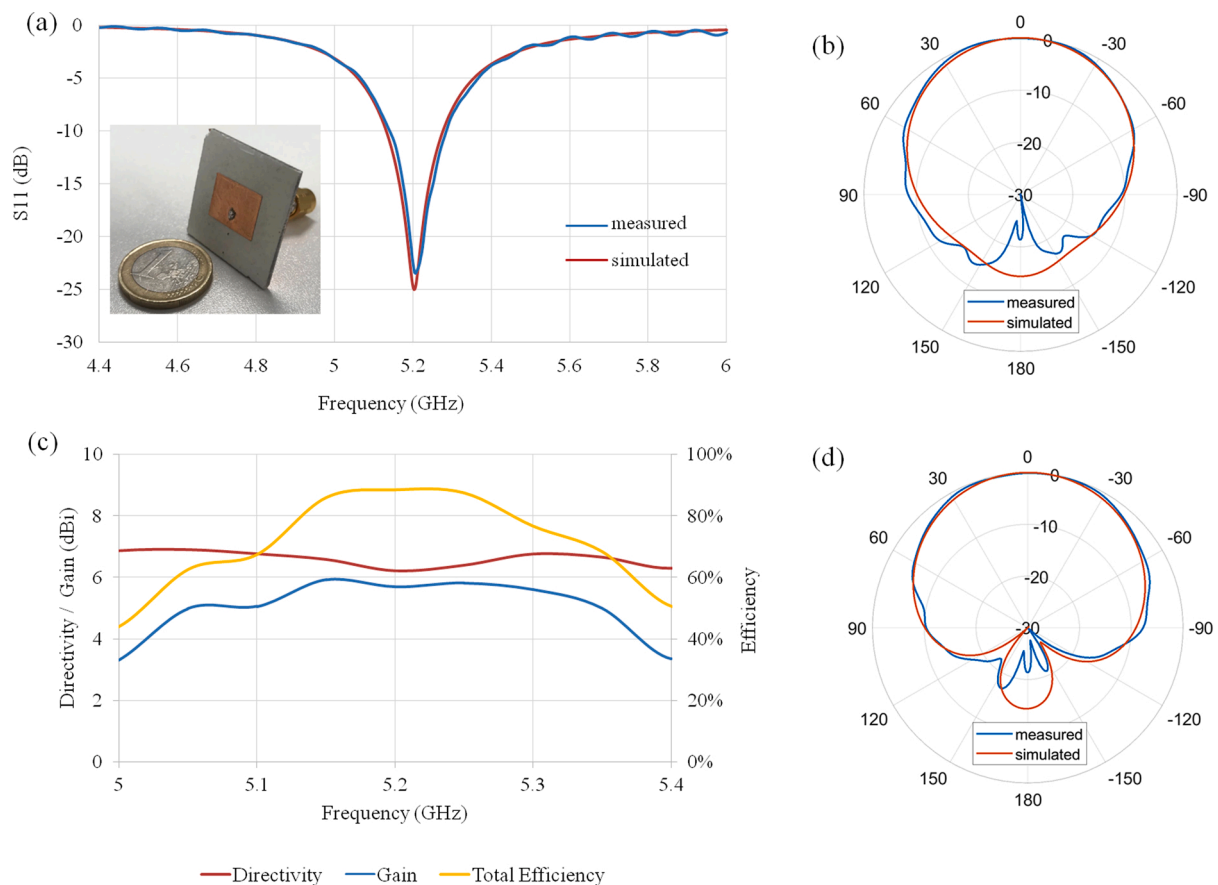


Fig. 6. (a)  $Z^*$  plot, and (b) Frequency dependence of  $Z''$  and  $M''$  for 65 wt%CSSO- 35 wt%KMO ceramic.





**Fig. 7.** (a) Measured S11 result of MSPA, compared with the simulation; (c) Measured far-field performance of the MSPA; Radiation patterns of the MSPA at (b) H-plane, (d) E-plane.

interests or personal relationships that could have appeared to influence the work reported in this paper.

## Acknowledgement

This work was supported by the National Natural Science Foundation of China (51672063), the training plan for young and middle-aged key teachers of Hangzhou Dianzi University, the Engineering and Physical Sciences Research Council of UK (EP/N010493/1 and EP/L017563/1) and the Henry Royce Institute for Advanced Materials (funded through EPSRC grants EP/R00661X/1, EP/S019367/1, EP/P02470X/1 and EP/P025285/1).

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